



**THE DATASHEET OF
CPPC7-A7BR-210.0TS**



Field Programmable Crystal Oscillator

Series CPP

- Programmed in the field with the PG-3200 oscillator programming instrument within seconds.
- Factory Programmable
- Can be programmed twice
- Standard Package Options
- Also available in 2.7V

Instrument Part Number:

CPPC1LZ-A5B6-XX.XXXX TS

CPP SERIES	C OUTPUT	1 PACKAGE STYLE	L VOLTAGE	Z ADDED FEATURE	A5 OPERATING TEMP	B6 STABILITY	XX.XXXX FREQUENCY	TS TRI-STATE
CPP	C = CMOS T = TTL	1 = Full Size 4 = Half Size 5 = 3.2x5 Ceramic 7 = 5x7 Ceramic 8 = PLASTIC SMD	Blank = 5V L = 3.3V R = 2.7V	Blank = Cut Tape B = Bulk T = Tube Z = Tape and Reel	Blank = 0°C~+70°C A3 = -55~+125°C A5 = -20°C~+70°C A7 = -40°C~+85°C	B6 = ±100PPM BP = ±50PPM BR = ±25PPM	0.500 ~ 133.000MHz	TS = Tri-State PD = Power Down

Specifications:

Description	Min	Typ	Max	Unit
Frequency Range: Programmable to any discrete frequency	0.500		133	MHz
Available Stability Options:	-100 -50 -25		+100 +50 +25	PPM
Programmable Supply Voltage:				
(1-133 MHz)	4.5	5.0	5.5	V
(1-100 MHz)	3.0	3.3	3.6	V
(1-66.0 MHz)	2.5	2.7	3.0	V
Operating Temperature Range Options:				
	-55		+125	°C
	-20		+70	°C
	-40		+85	°C
Storage Temperature:	-55		+125	°C
Aging: Ta=°25C,Vdd=5V/3.3V			±5	PPM/Year

Programmable Output Level:

CMOS/TTL

Operating Conditions:

Description	Min	Max	Unit
V_{DD} Supply Voltage	2.7	5.5	V
C_{TTL} Max capacitive load on outputs for TTL levels			
4.5V-5.5V V _{DD} , ≤ 40 MHz		50	pF
4.5V-5.5V V _{DD} , 40 - 133 MHz		25	pF
C_{CMOS} Max capacitive load on outputs for CMOS levels			
4.5V-5.5V V _{DD} , ≤ 66 MHz		50	pF
4.5V-5.5V V _{DD} , 66 - 133 MHz		25	pF
3.0V-3.6V V _{DD} , ≤ 40 MHz		30	pF
3.0V-3.6V V _{DD} , 40 - 100 MHz		15	pF
2.5-3.0V V _{DD} , ≤ 66 MHz		25	pF



Output Clock Switching Characteristics:

Description	Test Conditions	Min	Typ	Max	Unit
Duty Cycle: TTL @ 1.4V 4.5-5.5 V _{DD}	≤ 50 MHz, C _L = 50 pF	45	-	55	%
	50 - 66 MHz, C _L = 15 pF	45	-	55	%
	66 - 125 MHz, C _L = 25 pF	40	-	60	%
	125 - 133 MHz, C _L = 15 pF	40	-	60	%
Duty Cycle: CMOS @ V _{DD} /2 4.5-5.5 V _{DD} 3.0-3.6 V _{DD}	≤ 66 MHz, C _L ≤ 25 pF	45	-	55	%
	66 - 125 MHz, C _L ≤ 25 pF	40	-	60	%
	125 - 133 MHz, C _L ≤ 15 pF	60	-	60	%
	≤ 40 MHz, C _L ≤ 30 pF	45	-	55	%
Rise/Fall:	0.8V - 2.0V, 4.5 - 5.5 V _{DD} , C _L = 50 pF			1.8	ns
	0.8V - 2.0V, 4.5 - 5.5 V _{DD} , C _L = 25 pF			1.2	ns
	0.8V - 2.0V, 4.5 - 5.5 V _{DD} , C _L = 15 pF			0.9	ns
	0.2V - 0.8 * V _{DD} , 4.5 - 5.5 V _{DD} , C _L = 50 pF			3.4	ns
	0.2V - 0.8 * V _{DD} , 3.0 - 3.6 V _{DD} , C _L = 30 pF			4.0	ns
	0.2V - 0.8 * V _{DD} , 3.0 - 3.6 V _{DD} , C _L = 15 pF			2.4	ns
Start Up Time	From Power On	-	-	2	ms
Power Down Delay Time Synchronous Asynchronous	PWR_DOWN pin LOW to output Hi-Z, T = Frequency Oscillator Period		T/2	T+10	ns
			10	15	ns
Output Disable Time Synchronous Asynchronous	OE pin LOW to output Hi-Z, T = Frequency Oscillator Period		T/2	T+10	ns
			10	15	ns
Output Enable Time				100	ns
RMS Period Jitter	≤ 33.000 MHz		40	50	ps
	> 33.000 MHz		30	40	ps
Peak to Peak*	≤ 33.000 MHz		100	250	ps
	> 33.000 MHz		75	175	ps

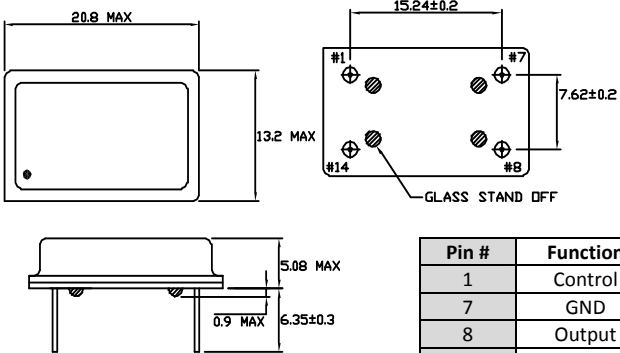
* Jitter Tested at > 1,000,000 samples, exceeding JEDEC std JESD65

Electrical Characteristics:

Description	Test Conditions	Min	Typ	Max	Unit
Input Characteristics (Pin 1):					
V _{IL} , Low-Level Input Voltage (To Tri-State or Power Down)	V _{DD} = 5.0 V	-	-	0.8	V
	V _{DD} = 3.3 V	-	-	0.2 * V _{DD}	V
	V _{DD} = 2.7 V	-	-	0.2 * V _{DD}	V
V _{IH} , High-Level Input Voltage (To Enable Output or Open)	V _{DD} = 5.0 V	2.0	-	-	V
	V _{DD} = 3.3 V	0.7 * V _{DD}	-	-	V
I _{IL} , Input Low Current	V _{IN} = 0 V	-	-	10	μA
I _{IH} , Input High Current	V _{IN} = V _{DD}	-	-	5	μA
Output Characteristics:					
V _{OL} , Low-Level Output Voltage	V _{DD} = 5.0 V, I _{OL} = 16mA	-	-	0.4	V
	V _{DD} = 3.3 V, I _{OL} = 8mA	-	-	0.4	V
V _{IHTTL} , High-Level Output Voltage	V _{DD} = 5.0 V, I _{OL} = -16mA	2.4	-	-	V
V _{IHCMOS} , High-Level Output Voltage	V _{DD} = 5.0 V, I _{OL} = -16mA	V _{DD} -0.4	-	-	V
	V _{DD} = 3.3 V, I _{OL} = -8mA	V _{DD} -0.4	-	-	V
Power Supply Current: (Unloaded)	V _{DD} = 5.0 V, F _O ≤ 133 MHz	-	-	45	mA
	V _{DD} = 3.3 V, F _O ≤ 100 MHz	-	-	25	mA
	V _{DD} = 2.7 V, F _O ≤ 66.0 MHz	-	-	20	mA
Standby Current:		-	10	50	μA
Tri-State Leakage Current	V _{DD} = 5.0 V	-	20	-	μA
Output Enable Mode:	Output is Tri-Stated				
Power Down Mode:	Output is Tri-Stated				

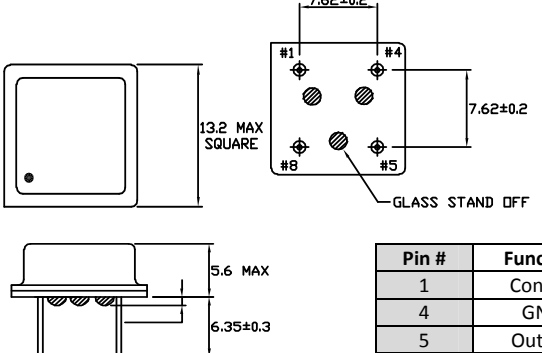
*Note: Bypass V_{DD} to GND with a $0.01\mu\text{F}$ capacitor

Style 1 Full Size 14 Pin Dip



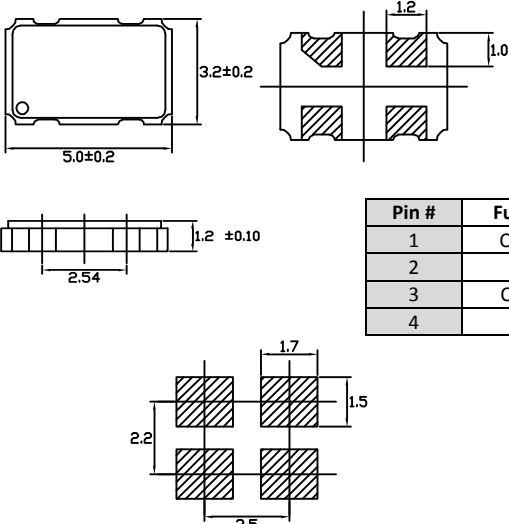
Pin #	Function
1	Control
7	GND
8	Output
14	V_{DD}

Style 4 Half Size 8 Pin Dip



Pin #	Function
1	Control
4	GND
5	Output
8	V_{DD}

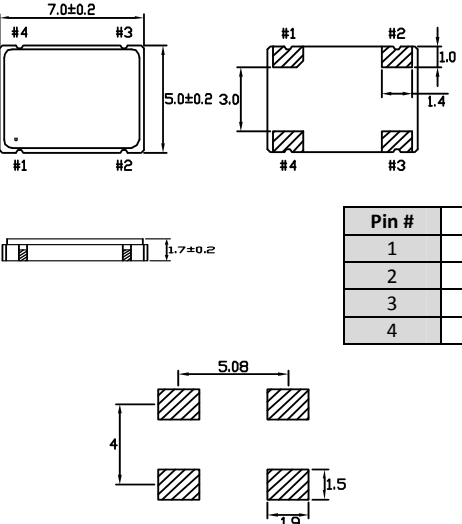
Style 5 3.2x5 Ceramic SMD



Pin #	Function
1	Control
2	GND
3	Output
4	V_{DD}

Recommended Solder Pad Layout

Style 7 5x7 Ceramic SMD

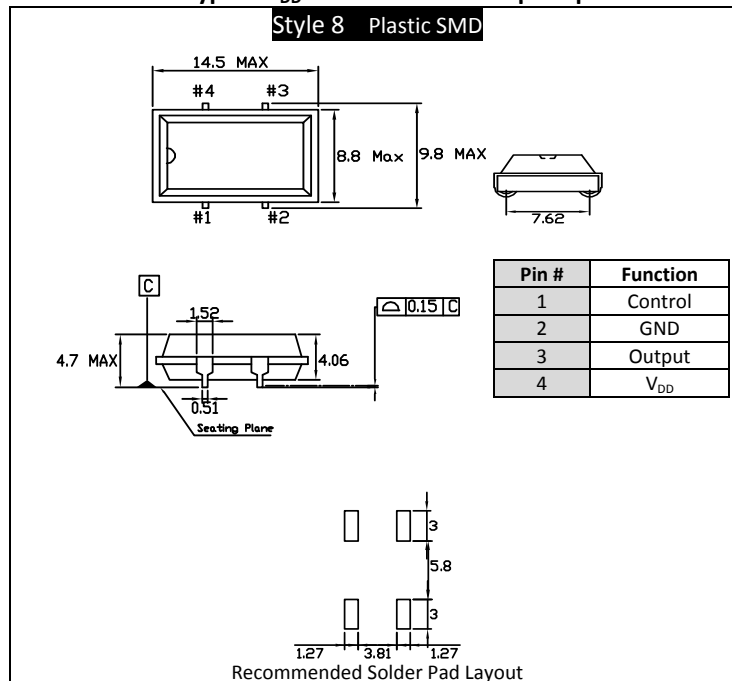


Pin #	Function
1	Control
2	GND
3	Output
4	V_{DD}

Recommended Solder Pad Layout



***Note: Bypass V_{DD} to GND with a 0.01 μ F capacitor**



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